

| Type | Hits | Search Text | DBs | Time Stamp | Comments | Error Definition |
|--------|------|---|---|------------------|----------|------------------|
| 76 BRS | 1175 | (silicon adj nitride) and (conduct\$4 near2 band) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 09:32 | | |
| 77 BRS | 37 | (silicon adj nitride) near20 (conduct\$4 near2 band) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 09:50 | | |
| 78 BRS | 35 | (silicon adj carbide) near20 (valence near2 band) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 20:00 | | |
| 79 BRS | 6 | 4980736.URPN. | USPAT | 2004/03/16 10:14 | | |
| 80 BRS | 6 | ("4887134" "4931661" "4933731" "4980736" "4982255" "5101255").PN. | USPAT | 2004/03/16 10:38 | | |
| 81 BRS | 2 | 6064091.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 20:34 | | |
| 82 BRS | 1 | 1999-371433.NRAN. | DERWENT | 2004/03/16 20:05 | | |
| 83 BRS | 1243 | (polycrystalline near2 (silicon or si)) and (250/\$ or 348/\$) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 20:38 | | |
| 84 BRS | 3 | (polycrystalline near2 (silicon or si)) and (250/\$ or 348/\$) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 20:35 | | |
| 85 BRS | 288 | (polycrystalline near2 (silicon or si) near10 substrate) and (250/\$ or 348/\$) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 20:36 | | |
| 86 BRS | 26 | (polycrystalline near2 (silicon or si) adj substrate) and (250/\$ or 348/\$) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 20:41 | | |
| 87 BRS | 684 | (polycrystalline adj (silicon or si) adj substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 21:20 | | |
| 88 BRS | 2 | 4496981.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 20:51 | | |

| | Type | Hits | Search Text | DBs | Time Stamp | Comments | Error Definition |
|-----|------|------|--|---|---------------------|----------|------------------|
| 89 | BRS | 4 | (microcrystalline adj (silicon or si) adj substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 22:00 | | |
| 90 | BRS | 10 | (microcrystalline near4 (silicon or si) adj substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 21:29 | | |
| 91 | BRS | 348 | (microcrystalline near10 (silicon or si) near10 substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 21:24 | | |
| 92 | BRS | 15 | ((microcrystal\$6 micro-crystal\$6 (micro adj crystal\$6)) near4 (silicon or si) adj substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 21:33 | | |
| 93 | BRS | 3429 | ((microcrystal\$6 micro-crystal\$6 (micro adj crystal\$6)) near4 (silicon or si)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 21:34 | | |
| 94 | BRS | 122 | ((microcrystal\$6 micro-crystal\$6 (micro adj crystal\$6)) near4 (silicon or si)) and (348/\$ or 250/\$) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 21:35 | | |
| 95 | BRS | 59 | microcrystalline near10 polycrystalline near10 monocrystalline | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 22:07 | | |
| 96 | BRS | 2 | 6077752.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 22:38 | | |
| 97 | BRS | 2 | 6157072.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 22:46 | | |
| 98 | BRS | 2 | 5635327.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 22:54 | | |
| 99 | BRS | 2 | 4980736.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 22:57 | | |
| 100 | BRS | 2 | 6,157,072.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 22:57 | | |

| Type | Hits | Search Text | DBs | Time Stamp | Comments | Error Definition |
|--------|-------|--|---|---------------------|----------|------------------|
| 63 BRS | 2 | 5122431.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 20:14 | | |
| 64 BRS | 129 | canon and (electric\$4 near2 field near2 (relax\$4 or reduc\$5)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 21:18 | | |
| 65 BRS | 2 | "09102627" | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 07:11 | | |
| 66 BRS | 0 | 9102627.URPN. | USPAT | 2004/03/15 21:18 | | |
| 67 BRS | 0 | 9102627.URPN. | USPAT | 2004/03/15 21:18 | | |
| 68 BRS | 1 | 1997-278784.NRAN. | DERWENT | 2004/03/15 21:18 | | |
| 69 BRS | 2 | 4980736.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 07:30 | | |
| 70 BRS | 21599 | (348/\$.ccls.) and (equal or "same" near5 (conduct\$4 adj band)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 07:33 | | |
| 71 BRS | 301 | ((348/\$.ccls.) and (equal or "same" near5 (conduct\$4 adj band))) and (amorphous) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 07:32 | | |
| 72 BRS | 23 | ((((348/\$.ccls.) and (equal or "same" near5 (conduct\$4 adj band))) and (amorphous)) and (sic or (si-c) or (silicon adj carbide)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 07:32 | | |
| 73 BRS | 1 | (348/\$.ccls.) and ((equal or "same") near5 (conduct\$4 adj band)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 07:34 | | |
| 74 BRS | 2926 | ((equal or "same" or level\$4) near5 (conduct\$4 adj band)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 07:35 | | |
| 75 BRS | 566 | ((equal or "same") near5 (conduct\$4 adj band)) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/16 09:31 | | |

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|--------|-------|--|---|---------------------|----------|------------------|
| 52 BRS | 218 | si-c and si-n | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 15:50 | | |
| 53 BRS | 87 | (si-c and si-n) and amorphous | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 16:05 | | |
| 54 BRS | 10548 | (c/si or (carbon near5 silicon) or (c near4 si)) near20 (ratio or fraction or percent\$4 or proportion\$6) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 19:31 | | |
| 55 BRS | 5545 | (c/si or (carbon near2 silicon) or (c near2 si)) near10 (ratio or fraction or percent\$4 or proportion\$6) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 16:07 | | |
| 56 BRS | 4372 | (c/si or (carbon near2 silicon) or (c near2 si)) near5 (ratio or fraction or percent\$4 or proportion\$6) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 16:07 | | |
| 57 BRS | 3270 | (c/si or (carbon near2 silicon) or (c near2 si)) near2 (ratio or fraction or percent\$4 or proportion\$6) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 16:07 | | |
| 58 BRS | 376 | (c/si or si/c) near5 (ratio or fraction or percent\$4 or proportion\$6) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 16:08 | | |
| 59 BRS | 45 | ((c/si or si/c) near5 (ratio or fraction or percent\$4 or proportion\$6)) and (348/\$ or 257/\$ or 250/\$) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 16:16 | | |
| 60 BRS | 58 | canon and (generat\$9 near2 multiplic\$8) | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 17:15 | | |
| 61 BRS | 2 | 6064091.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 17:15 | | |
| 62 BRS | 2 | 6,157,072.pn. | USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB | 2004/03/15 20:04 | | |